

# *High Frequency Circuit Analysis*

*Basic Concepts, Smith Chart, Scattering Parameters.*



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## *Outline*

### Introduction

High Frequency Analysis ; Graphic analysis

Scattering Parameters

High Frequency Circuits Measurement  
Techniques

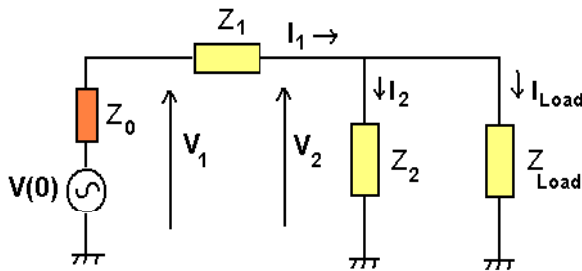


# Introduction



SSR

A conventional low frequency circuit consists of:



$$Z_E = Z_1 + Z_2 // Z_{LOAD}$$

$$\frac{V_2}{Z_2 // Z_{load}} = \frac{V_0 - V_2}{Z_1 + Z_0} \rightarrow V_2 = \frac{Z_2 // Z_{Load} + Z_1 + Z_0}{(Z_2 // Z_{Load})(Z_1 + Z_0)} V_0$$

Low frequency condition:

→ wires length  $\ll$  signal wavelength

High frequency condition

→ Wires length  $\propto$  signal wavelength

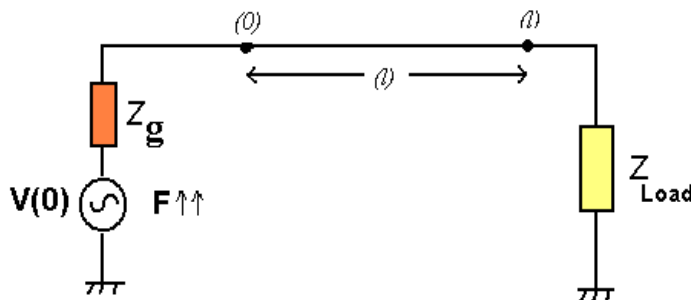


# Introduction



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A conventional High frequency circuit consists of:



The wires length is proportional to the signal wavelength

The wires current or potential phase depends on the distance (l)

$$\left. \begin{aligned} V(z) &= V^+ e^{-j\beta z} + V^- e^{j\beta z} \\ I(z) &= I^+ e^{-j\beta z} - I^- e^{j\beta z} \end{aligned} \right\}$$

The equivalent impedance depends on the position  $Z(d)$



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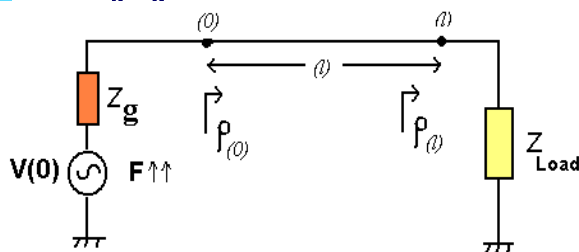
Introduction  
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 Techniques



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# High Frequency Analysis



The reflection coefficient is defined:

$$\rho(d) = \frac{V_{ref}}{V_{inc}} = \frac{V^- e^{j\beta(-z)}}{V^+ e^{-j\beta(-z)}} = |\rho_l| e^{-2j\beta z}$$

There is a quite easy relation between Z and  $\rho$ .

$$\left. \begin{aligned} V(d) &= V^+ e^{-j\beta z} + V^- e^{j\beta z} = V^+ e^{-j\beta z} [1 + \rho(l) e^{2j\beta(z-l)}] \\ I(d) &= \frac{V^+ e^{-j\beta z} - V^- e^{j\beta z}}{Z_o} = \frac{V^+}{Z_o} e^{-j\beta z} [1 - \rho(l) e^{2j\beta(z-l)}] \end{aligned} \right\} \rightarrow Z(z) = Z_o \frac{1 + \rho(z)}{1 - \rho(z)} = Z_o \frac{1 + \rho(l) e^{-2j\beta z}}{1 - \rho(l) e^{-2j\beta z}} = Z_o \frac{Z_l \cos \beta l + j Z_o \sin \beta l}{Z_o \cos \beta l + j Z_l \sin \beta l}$$

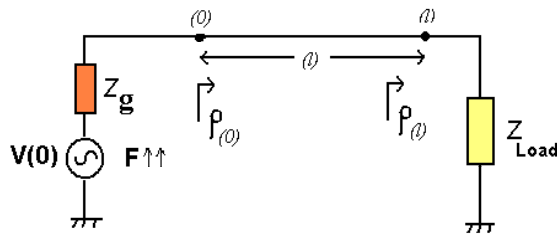
$$\boxed{Z(z) = Z_o \frac{1 + \rho(z)}{1 - \rho(z)}} \longleftrightarrow \boxed{\rho(z) = \frac{Z(z) - Z_o}{Z(z) + Z_o}}$$



# High Frequency Analysis



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VSWR:

$$VSWR = \frac{|V_{\max}|}{|V_{\min}|} = \frac{1 + |\rho(l)|}{1 - |\rho(l)|}$$

The transmitted Power:

$$P_T(z) = \frac{1}{2} \Re[V(z)I(z)^*] = \frac{1}{2} \Re \left[ V^+ e^{-j\beta z} [1 + \rho(l)e^{2j\beta(z-l)}] \frac{V^+}{Z_0} e^{+j\beta z} [1 - \rho(l)e^{-2j\beta(z-l)}] \right]$$

$$P_T(z) = \frac{1}{2Z_0} |V^+|^2 [1 - |\rho(l)|^2]$$

$V^+$  Easily solved from the relation:

$$V_g = -Z_g I(0) + V(0)$$

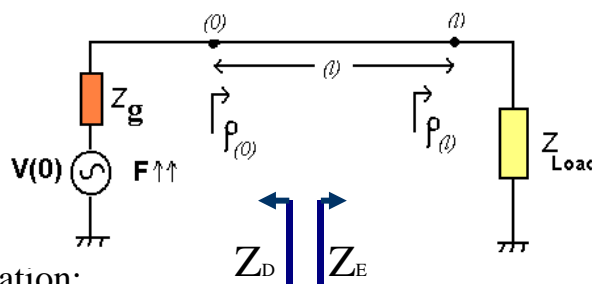
$$V(0) = Z_g \frac{V^+}{Z_0} [1 - \rho(l)e^{2j\beta(-l)}] + V^+ [1 + \rho(l)e^{2j\beta(-l)}]$$



# High Frequency Analysis



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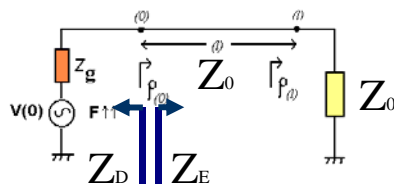


Power Adaptation:

When  $Z_E = Z_D^*$ , The power given to the load is the same as the power available at the generator.

$$P_T(z) = \frac{1}{2Z_0} |V^+|^2 [1 - |\rho(l)|^2] = \frac{1}{8 \Re(Z_g)} |V(0)|^2$$

- However,  $\rho$  could be different from zero.



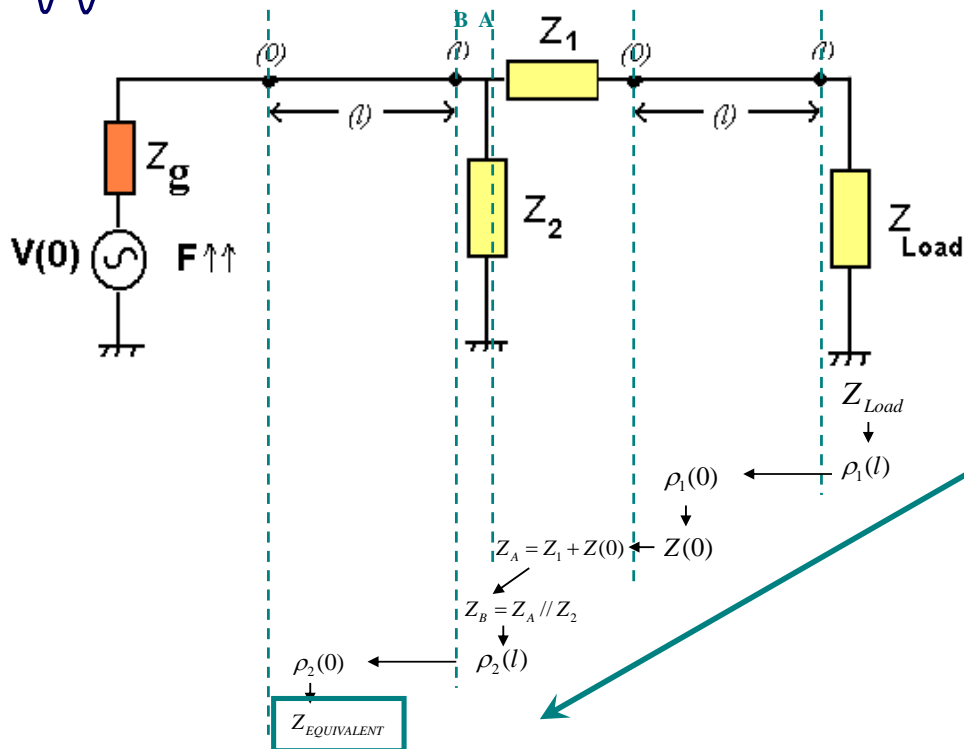
$$\rho = 0 \rightarrow \text{but } Z_E = Z_0 \neq Z_g$$



# High Frequency Analysis



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# High Frequency Analysis



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- A quite simple high frequency circuit could imply an embarrassing solution, with a lot of complex operations.
- With this analysis method, there is no way to notice the circuit behavior without analyzing it.

## Graphic Method of Solution:

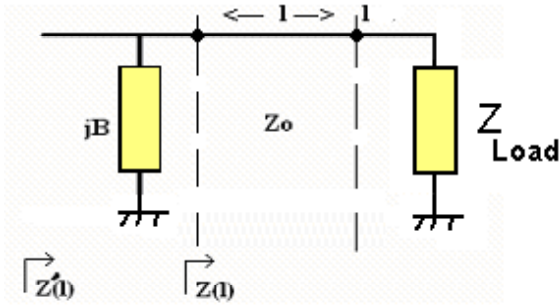
- In the 30's, Smith, engineer at Bell Laboratories developed an easy graphic method to solve high frequency circuits: The Smith Chart.
- This method allows us to obtain a general idea of what the circuit behavior is without a complete analysis.



# High Frequency Analysis: Smith Chart



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$Z$  and  $\rho$ , in complex form:

$$\bar{Z}(l) = \frac{Z(l)}{Z_o} = r + jx$$

$$\rho(l) = |\rho|e^{j\theta} = u + jv$$

Normalized impedance

Going on with the relation between  $\bar{Z}$  and  $\rho$  :

$$r + jx = \frac{1 + (u + jv)}{1 - (u + jv)}$$

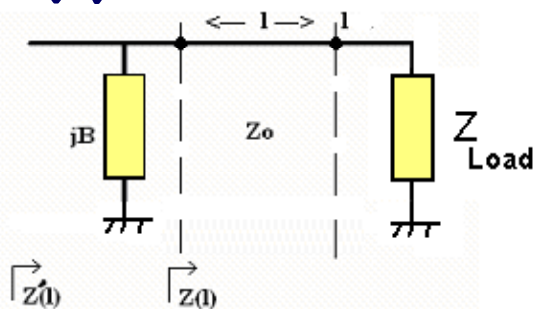
$$\left\{ \begin{array}{l} r = \frac{1 - (u^2 + v^2)}{(1 - u)^2 + v^2} \rightarrow \left(u - \frac{r}{1+r}\right)^2 + v^2 = \frac{1}{(1+r)^2} \\ x = \frac{2v}{(1 - u)^2 + v^2} \rightarrow (u - 1)^2 + \left(v - \frac{1}{x}\right)^2 = \frac{1}{x^2} \end{array} \right.$$



# High Frequency Analysis: Smith Chart



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$$r = \frac{1 - (u^2 + v^2)}{(1 - u)^2 + v^2} \rightarrow \left(u - \frac{r}{1+r}\right)^2 + v^2 = \frac{1}{(1+r)^2}$$

$$x = \frac{2v}{(1 - u)^2 + v^2} \rightarrow (u - 1)^2 + \left(v - \frac{1}{x}\right)^2 = \frac{1}{x^2}$$

Considering  $(u, v)$  the coordinates of our 2D coordinate system, the previous relation means:

For different values of  $r$  (real part of the normalized impedance) we will plot different circumferences, with features:

$$\text{Center: } c\left(\frac{r}{1+r}, 0\right) \text{ and radius: } R\left(\frac{1}{1+r}\right)$$

In the same way, for different values of  $x$  (imaginary part of the normalized impedance) we will plot different circumferences, with features:

$$\text{Center: } c\left(1, \frac{1}{x}\right) \text{ and radius: } R\left(\frac{1}{x}\right)$$

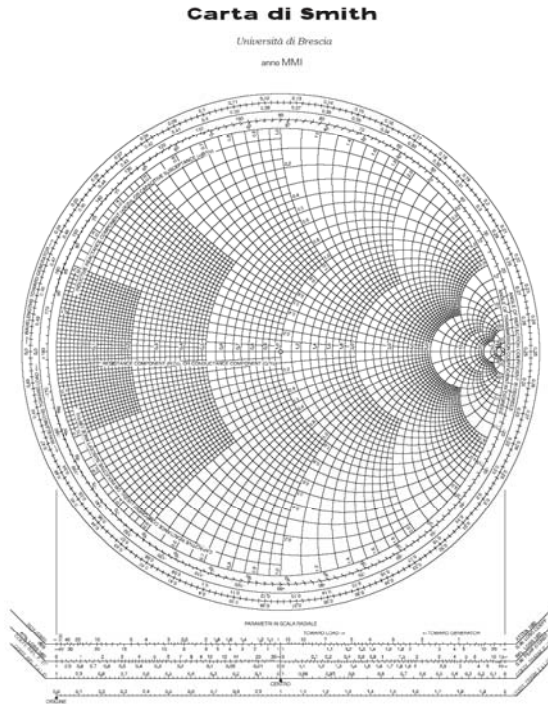




# High Frequency Analysis: Smith Chart



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$$r = \frac{1-(u^2+v^2)}{(1-u)^2+v^2} \rightarrow \left(u - \frac{r}{1+r}\right)^2 + v^2 = \frac{1}{(1+r)^2}$$

$$x = \frac{2v}{(1-u)^2+v^2} \rightarrow (u-1)^2 + \left(v - \frac{1}{x}\right)^2 = \frac{1}{x^2}$$

r: Center  $C\left(\frac{r}{1+r}, 0\right)$  and radius  $R\left(\frac{1}{1+r}\right)$

x: Center  $C\left(1, \frac{1}{x}\right)$  and radius  $R\left(\frac{1}{x}\right)$

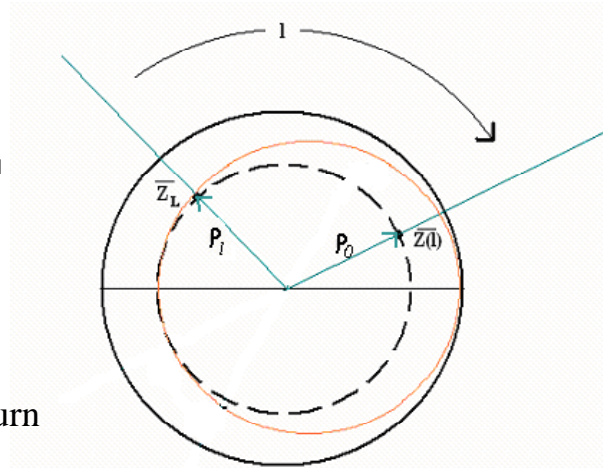
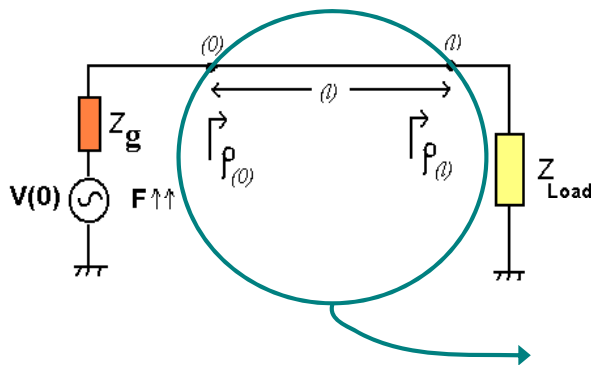


# High Frequency Analysis: Smith Chart



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First case of study: movement over wires



When moving towards generator, we turn towards right at the Smith Chart.

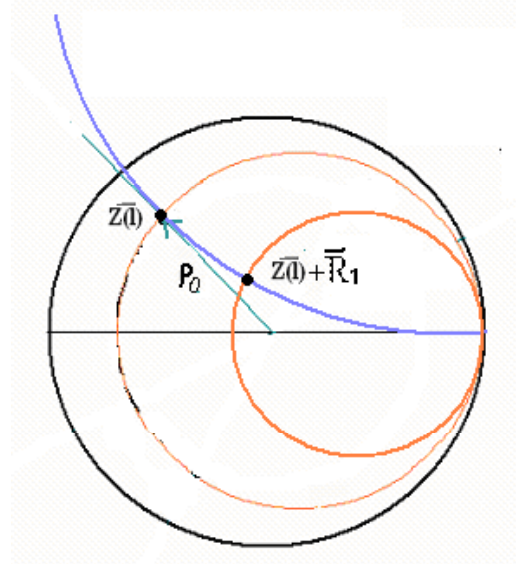
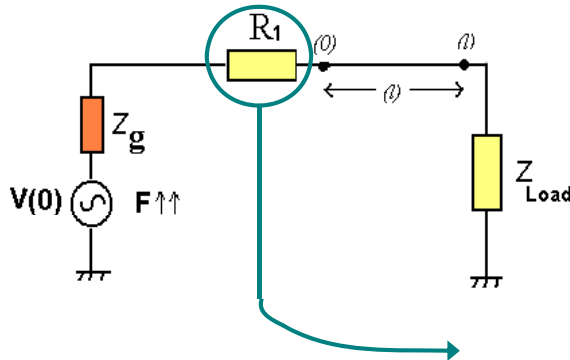


# High Frequency Analysis: Smith Chart



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Second case of study: adding series resistor.



When adding resistor, we keep the imaginary part and change into another real part circumference at the Smith Chart.

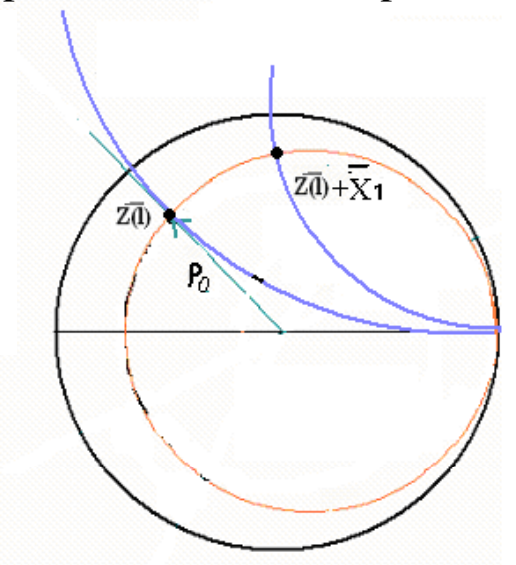
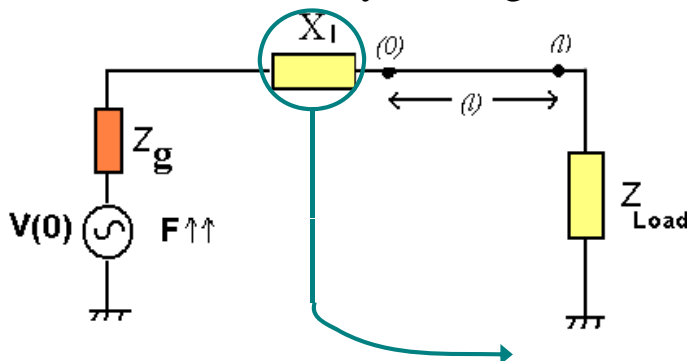


# High Frequency Analysis: Smith Chart



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Third case of study: adding series impedance with no real part.



When adding impedance with no real part, we keep the real part and change into another imaginary part curve at the Smith Chart.



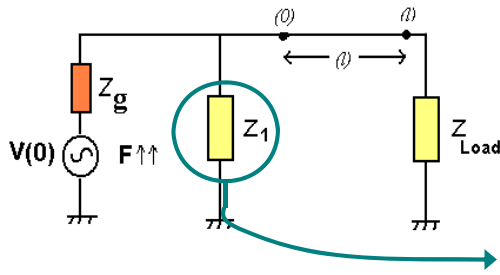


# High Frequency Analysis: Smith Chart



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Fourth case of study: adding parallel impedance.

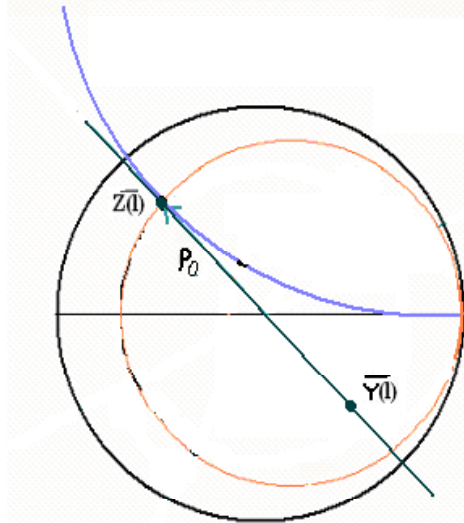


When adding parallel impedance, we transform impedance into admittance.

$$\bar{Z}(l) // \bar{Z}_1 = \bar{Y}(l) + \bar{Y}_1 \quad \bar{Z}(l) = \frac{1}{\bar{Y}(l)}$$

To obtain the admittance at the Smith Chart, we take the mirror point related to the center.

We solve as in the previous cases, taking admittance or impedance when necessary.

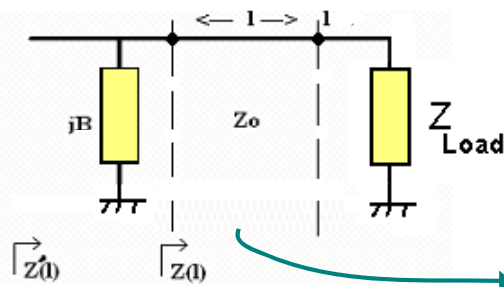


# High Frequency Analysis: Smith Chart

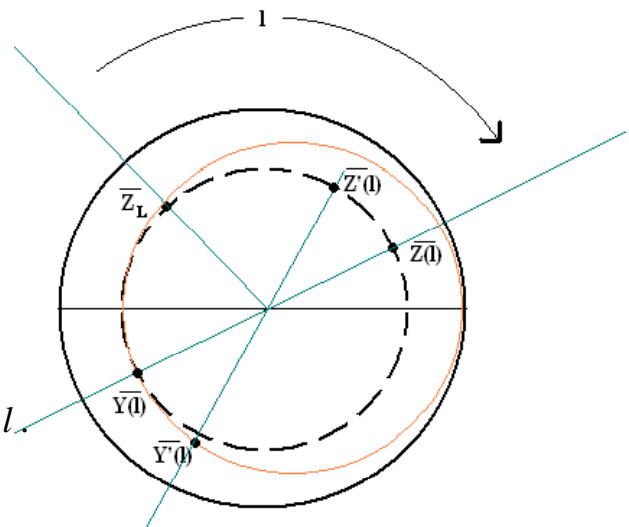


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Circuit example:



- 1.- Normalize  $Z_{load}$ .
- 2.- plot  $Z_{load}$  at the S. chart.
- 3.- move towards the generator length  $l$ .
- 4.- change  $Z(l)$  into  $Y(l)$ .
- 5.- add  $Y=jB$ ;  $Y'(l)=Y(l)+Y$ .
- 6.- change  $Y'(l)$  into  $Z'(l)$ .
- 7.- desnormalize  $Z'(l)$ .





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**Scattering Parameters**  
 High Frequency Circuits Measurement  
 Techniques



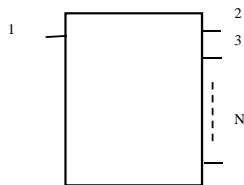
SSR



# Scattering Parameters



*Low frequency circuits* are usually characterized with their Z (impedance) parameters.



$$Z_i = \frac{V_i}{I_i} = \sum_{j=1}^N Z_{ij} \frac{I_j}{I_i} = Z_{ii} + \sum_{\substack{j=1 \\ i \neq j}}^N Z_{ij} \frac{I_j}{I_i}$$

$$\begin{bmatrix} V_1 \\ V_2 \\ \vdots \\ V_N \end{bmatrix} = \begin{bmatrix} Z_{11} & Z_{12} & \cdots & Z_{1N} \\ Z_{21} & Z_{22} & \cdots & Z_{2N} \\ \vdots & \vdots & \ddots & \vdots \\ Z_{N1} & Z_{N2} & \cdots & Z_{NN} \end{bmatrix} \begin{bmatrix} I_1 \\ I_2 \\ \vdots \\ I_N \end{bmatrix}$$

There are other possibilities, in order to reduce the complexity of analysis in any particular case, as F parameters, T parameters...

At *high frequency circuits* we define the S parameters. These parameters simplify measurements, as we analyze circuits in terms of transmission and reflection.



# Scattering Parameters

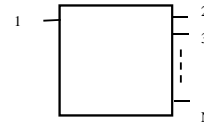


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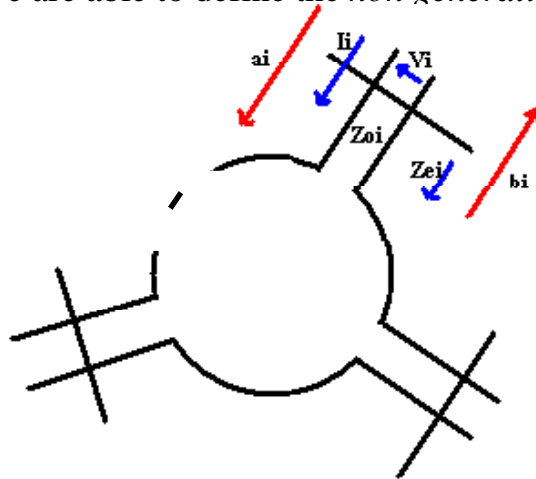
Considering the current and potential waves:

$$V_i(z) = V_i^+ e^{-j\beta z} + V_i^- e^{j\beta z}$$

$$I_i(z) = I_i^+ e^{-j\beta z} - I_i^- e^{j\beta z}$$



We are able to define the *non generalized power waves*.



$$a_i = \frac{V_i + Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$

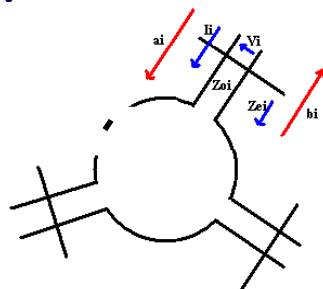
$$b_i = \frac{V_i - Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$



# Scattering Parameters



SSR



$$a_i = \frac{V_i + Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$

$$b_i = \frac{V_i - Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$

Taking into account, potential and current definitions:

$$V_i = V_i^+ + V_i^- \quad I_i = \frac{1}{Z_{oi}} [V_i^+ - V_i^-]$$

We obtain results below:

$$|a_i|^2 = \frac{|V_i^+|^2}{2Z_{oi}} = P_i^+ \quad |b_i|^2 = \frac{|V_i^-|^2}{2Z_{oi}} = P_i^-$$

Incident and reflected power at *i* port.

$$\frac{b_i}{a_i} = \frac{V_i^-}{V_i^+} = \frac{Z_{ei} - Z_{oi}}{Z_{ei} + Z_{oi}} = \rho_{vi}$$

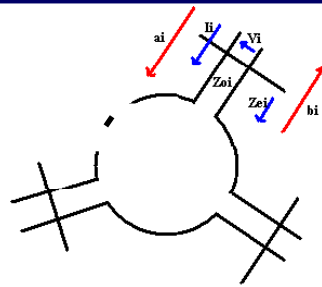
Reflection coefficient at *i* port.



# Scattering Parameters



SSR



$$a_i = \frac{V_i + Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$

$$b_i = \frac{V_i - Z_{oi} I_i}{\sqrt{8Z_{oi}}}$$

The scattering matrix exhibits the relation between  $a_i$  and  $b_i$ :

$$B = S \cdot A \quad \begin{pmatrix} b_1 \\ \dots \\ b_n \end{pmatrix} = \begin{pmatrix} S_{11} & \dots & S_{1n} \\ \dots & \dots & \dots \\ S_{n1} & \dots & S_{nn} \end{pmatrix} \begin{pmatrix} a_1 \\ \dots \\ a_n \end{pmatrix}$$

It is also possible to relate S parameters and Z parameters:

$$\left. \begin{aligned} B &= S \cdot A \\ V &= Z \cdot I \end{aligned} \right\} \begin{aligned} A &= F[V + G \cdot I] = F[Z + G]I \\ B &= F[V - G \cdot I] = F[Z - G]I \end{aligned} \quad \text{Where: } F = \text{diagonal} \left( \frac{1}{\sqrt{8Z_{oi}}} \right) \\ & \quad G = \text{diagonal}(Z_{oi})$$

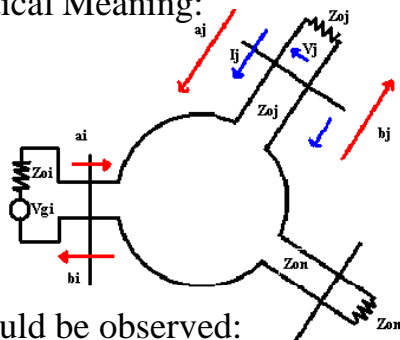


# Scattering Parameters



SSR

Practical Meaning:



$$b_i = \sum_j S_{ij} a_j$$

It could be observed:

$$\forall j \neq i \mapsto V_j = -Z_{oi} I_j \mapsto a_j = \frac{V_j + Z_{oj} I_j}{\sqrt{8Z_{oj}}} = 0$$

There is no input power when loading the  $j$  port with  $Z_{oj}$ .

$$b_i = S_{ii} a_i \xrightarrow{\substack{\forall a_j=0 \\ j \neq i}} S_{ii} = \frac{b_i}{a_i} = \frac{V_i - Z_{oi} I_i}{V_i + Z_{oi} I_i} = \frac{Z_{ei} - Z_{oi}}{Z_{ei} + Z_{oi}} = \rho_{vi}$$

$S_{ii}$  shows the reflection coefficient of the  $i$  port.

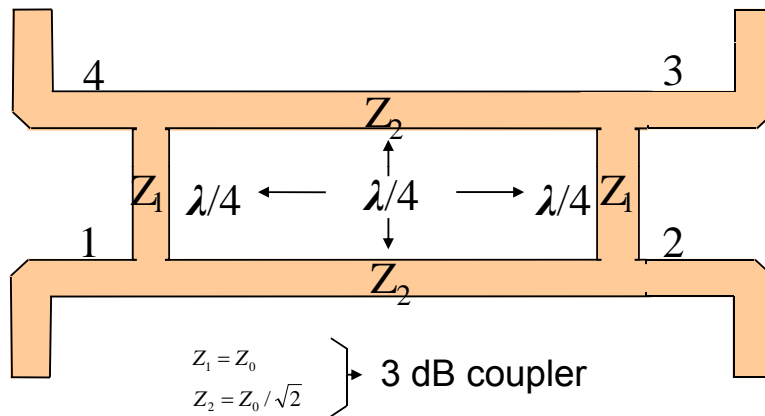
$$b_k = S_{ki} a_i \xrightarrow{\substack{\forall a_j=0 \\ j \neq i}} S_{ki} = \frac{b_k}{a_i} = \frac{V_k^- \sqrt{2Z_{oi}}}{V_i^+ \sqrt{2Z_{ok}}} = \frac{V_k^-}{V_i^+} \sqrt{\frac{Z_{oi}}{Z_{ok}}}$$

$S_{ki}$  is proportional to power transmission from  $i$  to  $k$  port.



SSR

# Scattering Parameters: example



$$S = \frac{1}{\sqrt{2}} \begin{bmatrix} 0 & -j & -1 & 0 \\ -j & 0 & 0 & -1 \\ -1 & 0 & 0 & -j \\ 0 & -1 & -j & 0 \end{bmatrix}$$

- Gate 1 : input
- Gate 2 : -90° output
- Gate 3 : -180° output
- Gate 4 : isolated port



SSR



Introduction

High Frequency Analysis; Graphic analysis

Scattering Parameters

High Frequency Circuits Measurement Techniques

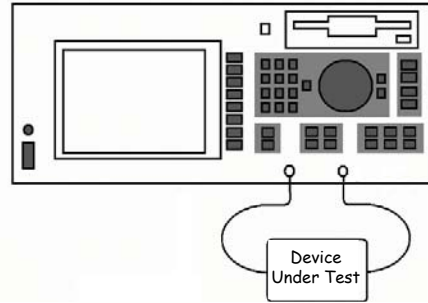
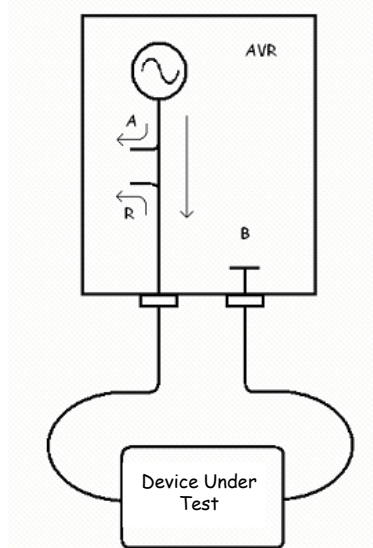


# High Frequency Circuits Measurement Techniques.



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High frequency circuits are measured with a *Network Analyzer*:



S parameters are measured and shown:

- Transmission ( $S_{12}$ )
- Reflection ( $S_{11}$ )
- Smith Chart ( $S_{11}$ )

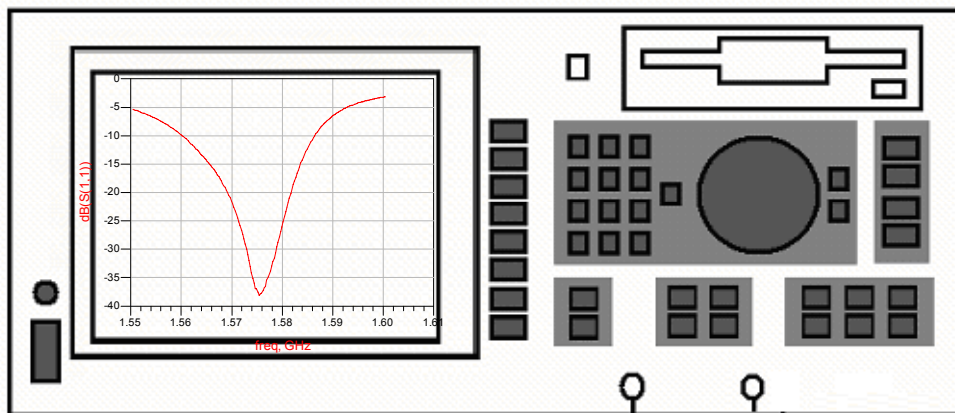


# High Frequency Circuits Measurement Techniques.



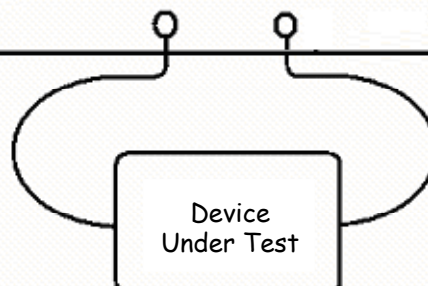
SSR

The Network Analyzer presents the transmission and reflection for a selected frequency span:



For the selected frequency span:

- Transmission ( $S_{12}$ )
- Reflection ( $S_{11}$ )





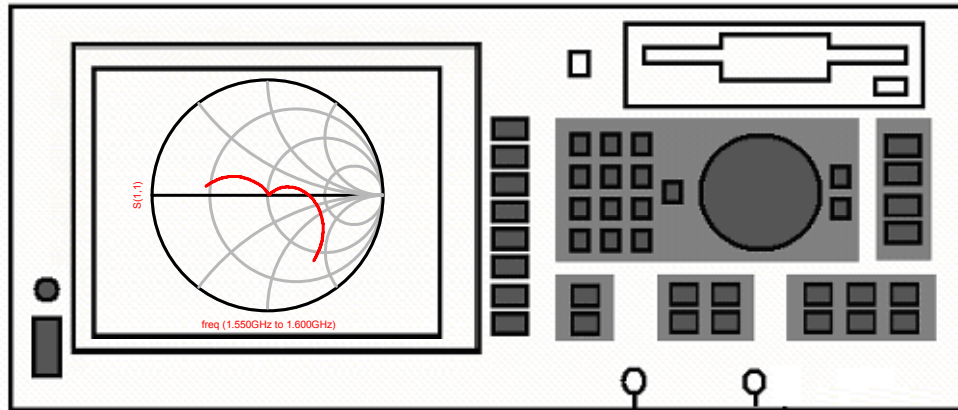


SSR

# High Frequency Circuits Measurement Techniques.



The Network Analyzer presents the transmission and reflection for a selected frequency span:



For the selected frequency span:

➤ Smith Chart ( $S_{11}$ )

